

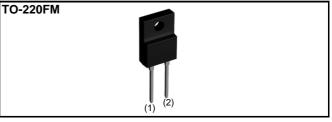
V _R	650V
١ _F	15A
Q _C	23nC

Features

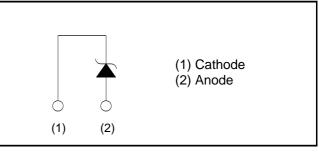
Construction

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

Outline



Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Taping code	С
	Marking	SCS215AM

• Absolute maximum ratings $(T_i = 25^{\circ}C)$

Silicon carbide epitaxial planer Schottky Diode

5				
Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V _{RM}	650	V	
Reverse voltage (DC)	V _R	650	V	
Continuous forward current	۱ _F	15* ¹	А	
Surge no repetitive forward current		55* ²	А	
	I _{FSM}	200* ³	А	
		43* ⁴	А	
Repetitive peak forward current	I _{FRM}	34* ⁵	А	
Total power disspation	P _D	39* ⁶	W	
Junction temperature	T _j	175	°C	
Range of storage temperature	T _{stg}	-55 to +175	°C	

*1 T_c=55°C *2 PW=8.3ms sinusoidal, T_j=25°C *3 PW=10 μ s square, T_j=25°C

*4 PW=8.3ms sinusoidal, T_j =150°C *5 T_c =100°C, T_j =150°C, Duty cycle=10%

*6 T_c=25°C

•Electrical characteristics ($T_j = 25^{\circ}C$)

Parameter	Symbol	Conditions	Values			L locit
Parameter			Min.	Тур.	Max.	Unit
DC blocking voltage	V _{DC}	I _R =0.3mA	600	-	-	V
Forward voltage	V _F	I _F =15A,T _j =25°C	-	1.35	1.55	V
		I _F =15A,T _j =150°C	-	1.55	-	V
		I _F =15A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	3	300	μA
		V _R =600V,T _j =150°C	-	45	-	μA
		V _R =600V,T _j =175°C	-	105	-	μA
Total capacitance	С	V _R =1V,f=1MHz	-	550	-	pF
		V _R =600V,f=1MHz	-	56	-	pF
Total capacitive charge	Q _c	V _R =400V,di/dt=350A/μs	-	23	-	nC
Switching time	t _c	V _R =400V,di/dt=350A/μs	-	18	-	ns

•Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
Falameter			Min.	Тур.	Max.	Unit
Thermal resistance	R _{th(j-c)}	-	-	3.2	3.8	°C/W

•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

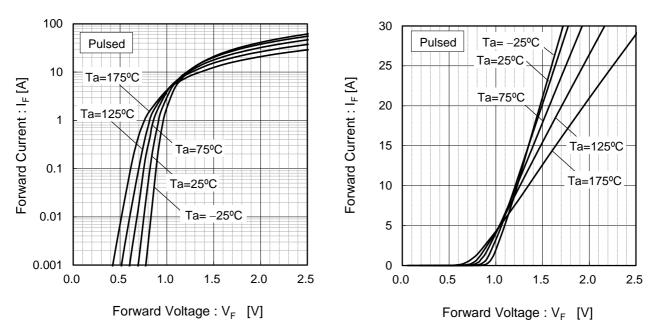
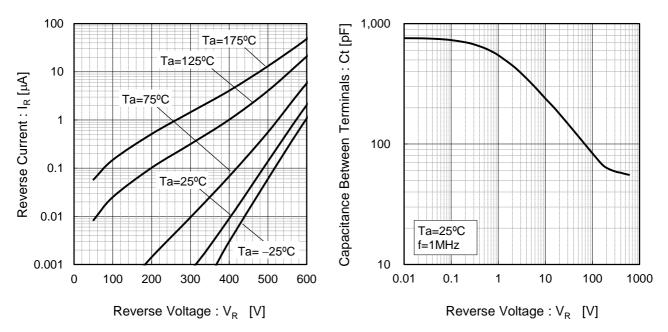


Fig.2 V_F - I_F Characteristics

Fig.3 V_R - I_R Characteristics

Fig.4 V_R-Ct Characteristics



•Electrical characteristic curves

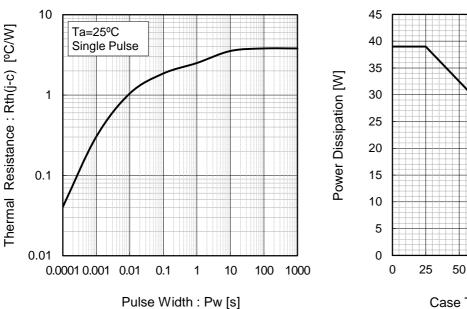


Fig.5 Thermal Resistance vs. Pulse Width

Fig.6 Power Dissipation

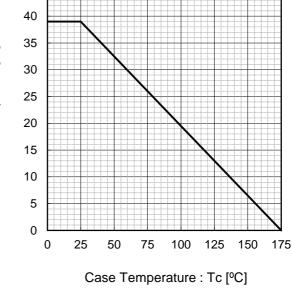
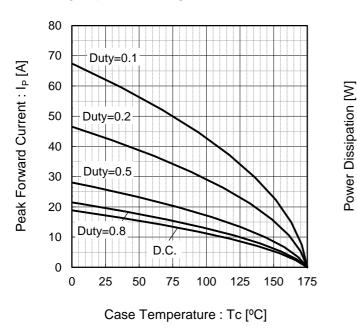
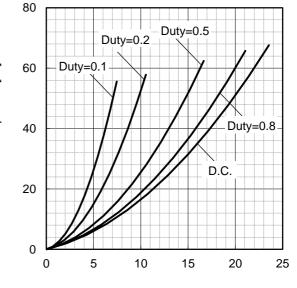


Fig.7 Ip-Tc Derating Curve

Fig.8 Io-Pf Characteristics

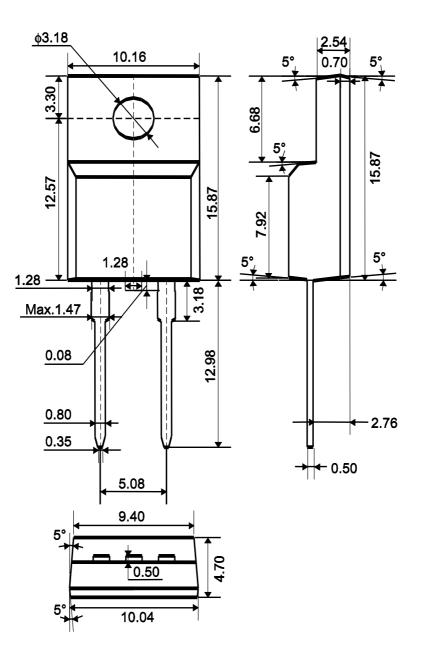




Average Rectified Forward Current : Io [A]

•Dimensions (Unit : mm)

TO-220FM (2pin)



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